DSC3F01

Silicon NPN epitaxial planar type

For high-frequency amplification DSC9F01 in SSSMini3 type package

■ Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- High transition frequency f_T
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

■ Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	15	V	
Collector-emitter voltage (Base open)	V_{CEO}	10	V	
Emitter-base voltage (Collector open)	V_{EBO}	3	V	
Collector current	$I_{\rm C}$	50	mA	
Collector power dissipation	P _C	100	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

■ Package

Code

SSSMini3-F2-B

- Pin Name
 - 1. Base
 - 2. Emitter
 - 3. Collector

■ Marking Symbol: C7

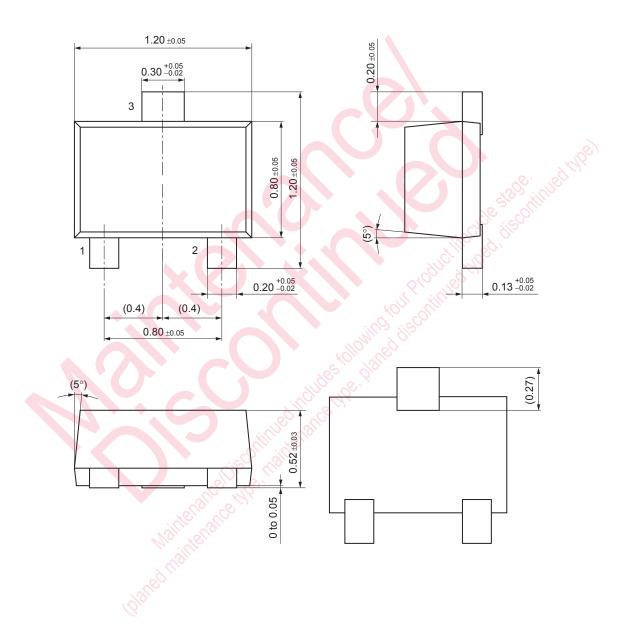
■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	10			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	3			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$			1	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 4 \text{ V}, I_C = 5 \text{ mA}$	75		220	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$			0.5	V
Transition frequency	f_T	$V_{CE} = 4 \text{ V}, I_{C} = 5 \text{ mA}$		1.9		GHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 4 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1.2		pF
Collector-base parameter	$r_{bb}' \cdot C_C$	$V_{CE} = 4 \text{ V}, I_{C} = 5 \text{ mA}, f = 31.9 \text{ MHz}$		12		ps
Reverse transfer capacitance (Common base)	C _{rb}	$V_{CE} = 4 \text{ V}, I_{C} = 0 \text{ , } f = 1 \text{ MHz}$		0.6		pF

 $Note)\ Measuring\ methods\ are\ based\ on\ JAPANESE\ INDUSTRIAL\ STANDARD\ JIS\ C\ 7030\ measuring\ methods\ for\ transistors.$

SSSMini3-F2-B

Unit: mm



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